NSN 5961-01-332-6637

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-6637 **Inclosure Material:** Glass **Overall Length:** 0.150 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.200 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 150.00 microamperes forward current, average peak **Capacitance Rating In Picofarads:** 12.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig:

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